

Supporting Information

A Selenophene Substituted Double-cable Conjugated Polymer Enables Efficient Single-Component Organic Solar Cells

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Contents

1. Materials and measurements
2. Synthesis of the monomer and polymer
3. OFETs
4. Single-component organic solar cells
5. NMR of the compounds and polymer
6. References

glancing angle of 0.2° with respect to the incoming beam. A small beam was used to get a better resolution. The primary slits have a size of 0.3 (horizontal) \times 0.5 mm (vertical), and the guard slits have a size of 0.1 (horizontal) \times 0.3 (horizontal) mm. The accumulation time was 6 h for each measurement. GIMAXS scattering curves (at Yoneda maximum) were obtained by using SAXSGUI program.

2. Synthesis of the monomer and polymer

((5-(5,7-bis(2-ethylhexyl)-4,8-dioxo-3-(5-(trimethylstannyl)selenophen-2-yl)-4H,8H-benzo[1,2-c:4,5-c']dithiophen-1-yl)selenophen-2-yl)dimethylstannyl)methylum (M2)

1,3-bis(2-ethylhexyl)-5,7-di(selenophen-2-yl)-4H,8H-benzo[1,2-c:4,5-c']dithiophene-4,8-dione (**M1**) (272 mg, 0.387 mmol) was dissolved in dry tetrahydrofuran under an inert atmosphere. The solution was cooled down to -78°C by using a liquid ethyl alcohol and then freshly made LDA (0.97 mmol in THF) was added drop-wise. The reaction was stirred at -78°C for 1h and trimethyltinchloride $[(\text{CH}_3)_3\text{SnCl}$, 1.16 mmol, 1 M in THF] was subsequently added. The mixture was stirred at room temperature overnight. The reactant was quenched by water, then extracted by diethyl ether (200 mL) and dried over anhydrous Na_2SO_4 . After removing solvent, the crude product was purified by recrystallization using ethyl alcohol to obtain **M2** (210 mg, yield 52.7%) as orange solid. ^1H NMR (CDCl_3 , 400 MHz): δ (ppm) 8.03 (d, 2H), 7.54 (d, 2H), 3.32 (t, 4H), 1.78 (s, 2H), 1.36 (m, 16H), 0.97-0.90 (m, 12H), 0.51-0.33 (t, 18H). ^{13}C NMR (CDCl_3 , 100 MHz): δ (ppm) 178.0, 153.0, 142.5, 137.5, 133.6, 133.1, 41.2, 33.7, 32.9, 28.9, 26.1, 23.0, 14.2, 10.9, 1.0, 0, -7.9. HRMS (MALDI-TOF) m/z : $[\text{M}]^+$, Calcd for $\text{C}_{40}\text{H}_{56}\text{O}_2\text{S}_2\text{Se}_2\text{Sn}_2$: 1033.019135, found: 1033.016784.

PBDBPBI-Se

To a degassed solution of monomer **M2** (15.71 mg, 15.27 μmol), **M3** (35.74 mg, 15.27 μmol) in toluene (4 mL) and DMF (0.4 mL), $\text{Pd}_2(\text{dba})_3$ (0.42 mg, 0.46 μmol) and PPh_3 (0.48 mg, 1.83 μmol) were added. The mixture was stirred at 115°C for 24

h, after which it was precipitated in methanol and filtered through a Soxhlet thimble. The polymer was extracted with acetone, hexane, dichloromethane and 1,1,2,2-tetrachloroethane. The solvent was evaporated and the polymer was precipitated in acetone. The polymer was collected by filtering over a 0.45 μm PTFE membrane filter and dried in a vacuum oven to yield PBDBPBI-Se (40.2 mg, 91.36%) as a dark solid. GPC (*o*-DCB, 140 $^{\circ}\text{C}$): $M_n = 47.1 \text{ kg mol}^{-1}$, $M_w = 82.4 \text{ kg mol}^{-1}$ and PDI = 1.75.

3. OFETs

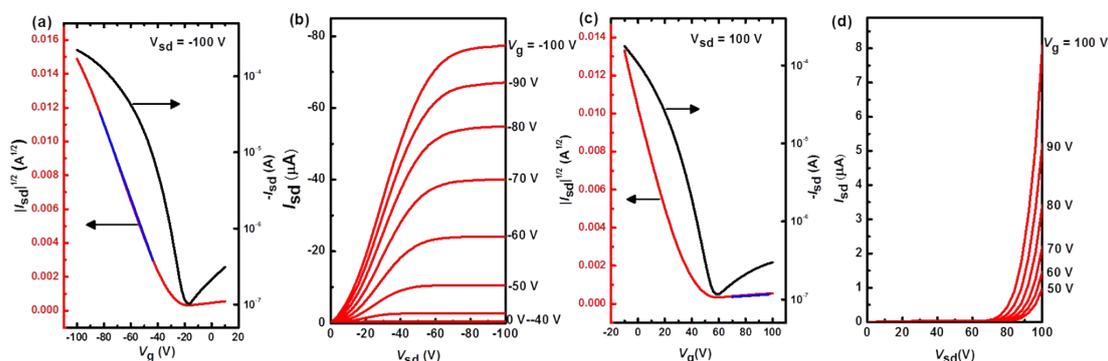


Figure S2. (a, c) Transfer and (b, d) output curves obtained from BGBC FET devices based on PBDBPBI-Se thin films fabricated from *o*-DCB after thermal annealed at 280 $^{\circ}\text{C}$. The blue lines in the figures were used to calculate (a) hole and (c) electron mobilities.

4. Single-component organic solar cells

Table S1. Characteristics of PBDBPBI-Se based solar cells spin coated from different solution, thickness and different thermal annealing temperature (10 min).

Solvent	TA [$^{\circ}\text{C}$]	Thickness [nm]	J_{sc} [mA cm $^{-2}$]	V_{oc} [V]	FF	PCE [%]
<i>o</i> -DCB	r. t.	65	5.08	0.90	0.31	1.44
<i>o</i> -DCB/DIO (0.5%)	r. t.	65	5.27	0.92	0.32	1.56
<i>o</i> -DCB/DIO (1%)	r. t.	65	4.39	0.93	0.30	1.23
<i>o</i> -DCB/DIO (0.5%)	r. t.	65	5.27	0.92	0.32	1.56
<i>o</i> -DCB/DIO (0.5%)	150	70	5.67	0.90	0.32	1.64
<i>o</i> -DCB/DIO (0.5%)	230	70	12.68	0.84	0.58	6.25
<i>o</i> -CB/DIO (0.5%)	280	70	12.34	0.80	0.56	5.51

<i>o</i> -CB/DIO (0.5%)	230	80	12.82	0.84	0.55	5.99
<i>o</i> -CB/DIO (0.5%)	230	70	12.68	0.84	0.58	6.25
<i>o</i> -CB/DIO (0.5%)	230	60	11.58	0.84	0.61	5.92
<i>o</i> -CB/DIO (0.5%)	230	50	11.08	0.84	0.63	5.82

Table S2. Photovoltaic performances of 8 devices based on PBDBPBI-Se fabricated from *o*-DCB/DIO (0.5%) without thermal annealing.

No.	J_{sc} [mA/cm ²]	V_{oc} [V]	FF	PCE [%]
1	5.39	0.91	0.34	1.65
2	5.27	0.92	0.32	1.56
3	5.30	0.92	0.32	1.54
4	5.26	0.92	0.32	1.55
5	5.28	0.92	0.32	1.55
6	5.43	0.92	0.33	1.62
7	5.41	0.92	0.33	1.62
8	5.05	0.91	0.33	1.51
average	5.30 ± 0.11	0.92 ± 0.004	0.33 ± 0.007	1.58 ± 0.05

Table S3. Photovoltaic performances of 8 devices based on PBDBPBI-Se fabricated from *o*-DCB/DIO (0.5%) and thermal annealed at 230 °C for 10 min.

No.	J_{sc} [mA/cm ²]	V_{oc} [V]	FF	PCE [%]
1	11.75	0.85	0.61	6.05
2	12.83	0.84	0.56	6.07
3	12.79	0.83	0.57	6.01
4	12.93	0.83	0.57	6.12
5	12.68	0.84	0.58	6.25
6	12.69	0.84	0.58	6.22
7	12.58	0.84	0.58	6.12
8	12.61	0.84	0.58	6.15
average	12.61 ± 0.34	0.84 ± 0.01	0.58 ± 0.01	6.12 ± 0.08

6. References

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